NSN 5961-01-185-7405

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-185-7405 **Inclosure Material:** Metal **Overall Length:** 2.845 inches **Overall Height:** 0.670 inches **Overall Width:** 0.890 inches **End Application:** B-1b **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 300.00 amperes forward current, average preset **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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